

Special Issue

Wide-Bandgap Semiconductor Materials in Power Electronics

Message from the Guest Editor

Wide bandgap (WBG) semiconductor materials, such as silicon carbide (SiC), gallium nitride (GaN) or gallium oxide (Ga₂O₃), allow power electronic components to be smaller, faster, more reliable, and more efficient than their silicon (Si)-based counterparts. Currently, around half of the world's total energy consumption of any kind is electrical, and it is estimated that 80% of all electricity will flow through a power-electronic device by 2030. Yet, there is a lot of room for basic and material science; WBG materials are indeed all over the place; almost the entire Earth crust is formed by wide bandgap oxides, and there are many chalcogenides, halides, organic and biomaterials that are also wide bandgap materials, among many other possibilities. The present Special Issue is devised as a collection of articles, reporting both concise reviews of recently obtained results, and new findings produced in this broad research area.

Guest Editor

Dr. Amador Pérez Tomás

1. Catalan Institute of Nanoscience and Nanotechnology (ICN2), Autonomous University of Barcelona, 08193 Barcelona, Spain
2. Institute of Microelectronics of Barcelona (IMB-CNM-CSIC), Autonomous University of Barcelona, 08193 Barcelona, Spain

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Editorial Office
MDPI, Grosspeteranlage 5
4052 Basel, Switzerland
Tel: +41 61 683 77 34
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Message from the Editor-in-Chief

As the world of science becomes ever more specialized, researchers may lose themselves in the deep forest of the ever increasing number of subfields being created. This open access journal Applied Sciences has been started to link these subfields, so researchers can cut through the forest and see the surrounding, or quite distant fields and subfields to help develop his/her own research even further with the aid of this multi-dimensional network.

Editor-in-Chief

Prof. Dr. Giulio Nicola Cerullo
Dipartimento di Fisica, Politecnico di Milano, Piazza L. da Vinci 32,
20133 Milano, Italy

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